



# CFK2062-P1

800 to 900 MHz +30 dBm Power GaAs FET





# **Product Specifications December 1997** (1 of 4)

### **Features**

- ☐ High Gain
- ☐ +30 dBm Power Output
- **☐** Proprietary Power FET Process
- **□** >40% Linear Power Added Efficiency
- ☐ Surface Mount SO-8 Power Package

# **Applications**

- ☐ ISM Band Base Stations and Terminals
- ☐ Cellular Base Stations and Terminals
- **☐** Wireless Local Loop

### **Description**

The CFK2062-P1 is a high-gain FET intended for driver amplifier applications in high-power systems, and output stage usage in medium power applications at power levels up to +30 dBm. The device is easily matched and provides excellent

**Specifications** (TA = 25°C) The following specifications are guaranteed at room temperature in Celeritek test fixture at 850 MHz.

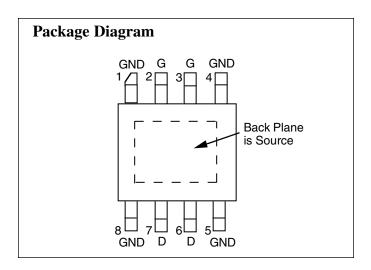
Parameters	Conditions	Min	Тур	Max	Units
$\overline{V_d}$ = 8V, $I_d$ = 400 mA (Quiescent)					
P <sub>-1 dB</sub>		29.0	30.0	_	dBm
SSG		18.0	20.0		dB
3rd Order Products (1)			30		dBc
Efficiency	@ P1dB	_	40		%
$V_d = 5V$ , $I_d = 600$ mA (Quiescent)					
P <sub>-1 dB</sub>			29.5	_	dBm
SSG		_	19.0	_	dB

Parameters	Conditions	Min	Тур	Max	Units
g <sub>m</sub>	Vds = 2.0V, Vgs = 0V		650		mS
I <sub>dss</sub>	Vds = 2.0V, Vgs = 0V	_	1.4	_	A
$\overline{\mathrm{V_{p}}}$	Vds = 3.0V, Ids = 25  mA	_	-1.8		Volts
BV <sub>GD</sub>	Igd = 2.5  mA	15	17	_	Volts
$\Theta_{JL}$ (2)	@150°C TCH	_	12	_	°C/W

#### **Absolute Maximum Ratings**

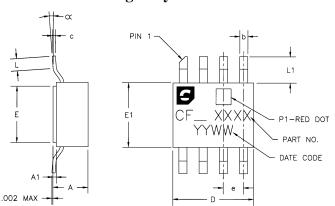
Parameter	Symbol	Rating
Drain-Source Voltage	$v_{DS}$	$10V^{(3)}$
Gate-Source Voltage	$v_{GS}$	-5V
Drain Current	$I_{DS}$	Idss
Continuous Dissipation	$P_{T}$	6W
Channel Temperature	$T_{CH}$	175°C
Storage Temperature	$T_{STG}$	-65°C to +175°C

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linearity at 1 Watt. Manufactured in Celeritek's proprietary power FET process, this device is assembled in an industry standard surface mount SO-8 power package that is compatible with high volume, automated board assembly techniques.

# **SO-8 Power Package Physical Dimensions**



DIMENSION	MINIMUM	NOMINAL	MAXIMUM
Α		.086[2.184]	.100[2.540]
A1	.005[.1270]	.008[.2032]	.011[.2794]
b	.017[.4318]	.020[.5080]	.023[.5842]
C-	.007[.1778]	.008[2032]	.009[.2286]
D	.195[4.953]	.200[5.080]	.205[5.207]
E	.135[3.429]	.140[3.556]	.145[3.683]
E1	.155[3.937]	.160[4.064]	.165[4.191]
е		.050[1.270]	
L	.020[.5080]		.040[1.016]
L1	.055[1.397]	.065[1.651]	.075[1.905]
α	0,		8.

DIMENSIONS IN INCHES [MILIMETERS]

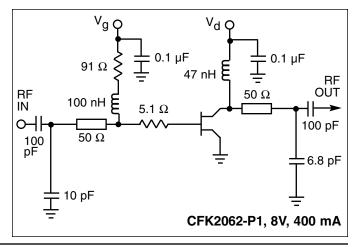
Phone: (408) 986-5060

#### Notes:

- 1. Sum to two tones with 1 MHz spacing = 25 dBm.
- 2. See thermal considerations information on page 4.
- 3. Maximum potential difference across the device (Vd + Vg) cannot exceed 12V.

Typical Sca	attering	Parameters	(TA = 25	$5^{\circ}$ C, Vds = 5 V,	Ids = 600  mA)				
Frequency S <sub>11</sub>		11	s <sub>21</sub>		S <sub>1</sub>	S <sub>12</sub>		S <sub>22</sub>	
(GHz)	Mag	Ang	Mag	Ang	Mag	Ang	Mag	Ang	
0.6	0.927	-129.75	8.7	102.7	0.024	21.95	0.576	-178.45	
0.7	0.921	-138.64	7.587	97.2	0.025	16.98	0.588	179.24	
0.8	0.919	-145.3	6.726	92.32	0.025	12.77	0.597	177.37	
0.9	0.919	-150.58	6.02	88.2	0.025	12.07	0.6	176.07	
1.0	0.914	-154.69	5.449	84.82	0.025	8.72	0.6	175.04	
1.1	0.911	-157.8	5.018	82.03	0.026	7.57	0.597	174.42	
1.2	0.91	-160.09	4.678	79.43	0.027	6.24	0.594	173.69	
1.3	0.908	-162.37	4.423	76.85	0.027	4.79	0.588	172.66	
1.4	0.904	-164.19	4.225	74.15	0.028	2.63	0.578	171.66	
1.5	0.9	-166.3	4.066	71.35	0.029	2.62	0.567	170.4	
2.0	0.883	177.09	3.605	52.62	0.05	-10.6	0.512	154.61	
2.5	0.887	150.54	2.944	28.96	0.035	-30.13	0.539	128.94	
3.0	0.917	135.01	2.081	13.19	0.03	-41.27	0.623	118.42	
3.5	0.932	137.14	1.635	8.18	0.028	-41.69	0.643	124.18	
4.0	0.913	143.42	1.641	3.36	0.032	-41.15	0.557	131.38	
			(TA = 25	$S^{\circ}C$ , $Vds = 8 V$ ,	Ids = 400  mA)				
0.6	0.91	-131.25	9.129	100.5	0.026	17.07	0.521	-174.04	
0.7	0.905	-139.87	7.943	95.18	0.026	13.22	0.534	-176.65	
0.8	0.906	-146.47	7.028	90.26	0.026	11.05	0.543	-178.82	
0.9	0.906	-151.44	6.281	86.16	0.027	8.59	0.547	179.94	
1.0	0.904	-155.33	5.68	82.61	0.027	6.34	0.548	178.8	
1.1	0.903	-158.37	5.226	79.83	0.027	3.72	0.547	178.18	
1.2	0.903	-160.69	4.866	77.15	0.027	3.34	0.544	177.57	
1.3	0.899	-167.2	4.574	74.6	0.028	0.5	0.538	176.86	
1.4	0.897	-164.68	4.366	71.76	0.029	1.6	0.53	176.13	
1.5	0.892	-166.63	4.203	68.96	0.03	-0.36	0.519	174.97	
2.0	0.877	176.74	3.696	50.36	0.035	-13.77	0.463	160.21	
2.5	0.882	150.43	3.014	26.66	0.036	-31.65	0.486	133.49	
3.0	0.915	135.06	2.136	10.26	0.031	-46.6	0.579	121.99	
3.5	0.93	137.37	1.662	4.59	0.027	-43.86	0.611	128.44	
4.0	0.912	143.75	1.642	-0.35	0.031	-43.95	0.541	137.64	

**RF Match** Data shown in the performance graphs was taken in the test circuit shown at right. Layout is important for proper operation. Phase length of input and output  $50\Omega$  line varies as a function of exact desired frequency of operation. Output shunt inductor effects output performance. Celeritek recommends the use of a high impedance printed inductor Lambda/4 in length.Please contact the factory for an evaluation board and/or more detailed application support.







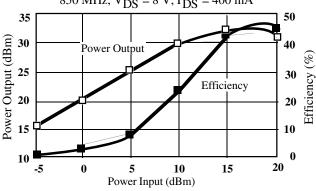


# **Product Specifications - December 1997**

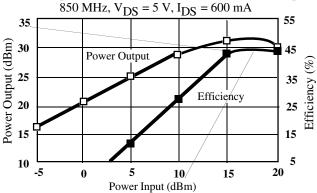
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# **Typical Performance**

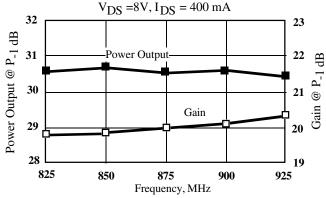
Power Output & Power Added Efficiency vs Power Input  $850 \text{ MHz}, V_{DS} = 8 \text{ V}, I_{DS} = 400 \text{ mA}$ 



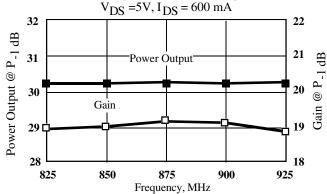
Power Output & Power Added Efficiency vs Power Input



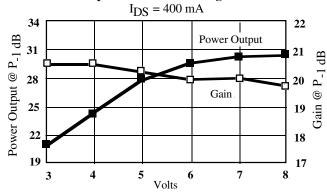
**Power Output and Gain vs Frequency** 



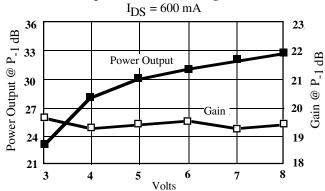
Power Output and Gain vs Frequency



#### Power Output and Gain vs Voltage @ 850 MHz



Power Output and Gain vs Voltage @ 850 MHz  $\,$ 

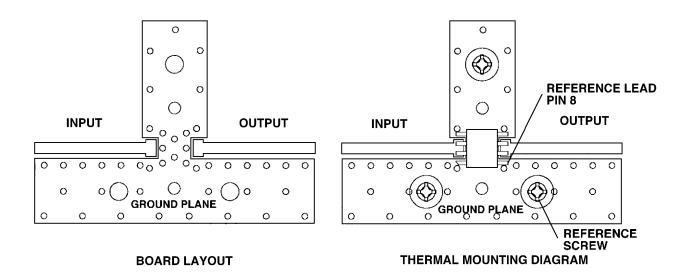


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#### **Thermal Considerations**

The data shown was taken on a 31 mil thick FR-4 board with 1 ounce copper on both sides. The board was mounted to a base-plate with 3 screws as shown. The screws bring the top side copper temperature to the same value as the baseplate. The thermal resistance to the indicated reference lead,  $\Theta_{II}$ , is 12°C/W. The thermal resistance to the reference screw is 14°C/W.

- 1. Use 1 or 2 ounce copper if possible.
- 2. Solder all eight leads of the CFK2062-P1 package to the appropriate electrical connection.
- 3. Solder the copper pad on the backside of the CFK2062-P1 package to the ground plane.
- 4. Use a large ground pad area with many plated through-holes as shown.
- 5. If possible, use at least one screw no more than 0.2 inches from the CFK2062-P1 package to provide a low thermal resistance path to the baseplate of the package.



## **Ordering Information**

The CFK2062-P1 power stage is available in a SO-8 surface mount package. Devices are available in tape and reel. Ordering part numbers are listed.

<u>Part Number for Ordering</u> <u>Function</u> <u>Package</u>

CFK2062-P1 800 - 900 MHz Power Stage SO-8 surface mount power package

CFK2062-P1-000T 800 - 900 MHz Power Stage SO-8 surface mount power package in tape and reel

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